

View Online at <https://aerobasegroup.com/nsn/5961-01-372-1078>

**Inclosure Material:**

Ceramic

**End Application:**

Alr62 f111d/e

**Component Name And Quantity:**

6 transistor

**Mounting Method:**

Terminal

**Features Provided:**

Burn in and electrostatic sensitive

**Semiconductor Material:**

Silicon single transistor

**Voltage Rating In Volts Per Characteristic:**

60.0 breakdown voltage, collector-to-emitter, base open single transistor and 60.0 breakdown voltage, collector-to-base, emitter open single transistor and 5.0 breakdown voltage, emitter-to-base, collector open single transistor

**Current Rating Per Characteristic:**

10.00 microamperes zero-gate-voltage source current preset single transistor

**Power Rating Per Characteristic:**

720.0 milliwatts small-signal input power, common-collector absolute single transistor

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius ambient air

**Test Data Document:**

15786-325726 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

**Terminal Type And Quantity:**

14 printed circuit

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

A110a0